

Technical Data
Datasheet 4290 REV. –

SILICON CARBIDE 3-PHASE HALF WAVE BRIDGE

DESCRIPTION: 1200-VOLT, 5 AMP POWER SILICON CARBIDE 3-PHASE HALF WAVE BRIDGE IN A HERMETIC 5-PIN TO-258 (MO-078) PACKAGE.

FEATURES:

- NO RECOVERY TIME OR REVERSE RECOVERY LOSSES
- NO TEMPERATURE INFLUENCE ON SWITCHING BEHAVIOR

MAXIMUM RATINGS

ALL RATINGS ARE @ $T_C = 25\text{ }^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	1200	Volts
MAXIMUM DC OUTPUT CURRENT (With $T_C = 65\text{ }^\circ\text{C}$) PER LEG	I_O	5	Amps
MAXIMUM REPETITIVE FORWARD SURGE CURRENT ($t = 8.3\text{ms}$, Sine) per leg, $T_C = 25\text{ }^\circ\text{C}$	I_{FRM}	30	Amps
MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT ($t = 10\mu\text{s}$, pulse) per leg, $T_C = 25\text{ }^\circ\text{C}$	I_{FSM}	100	Amps
MAXIMUM JUNCTION CAPACITANCE ($V_f=5\text{V}$) per leg	C_T	450	pF
MAXIMUM POWER DISSIPATION, $T_C = 25\text{ }^\circ\text{C}$	P_d	30	W
MAXIMUM THERMAL RESISTANCE, Junction to Case	$R_{\theta JC}$	1.2	$^\circ\text{C/W}$
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top, Tstg	-55 to +175	$^\circ\text{C}$

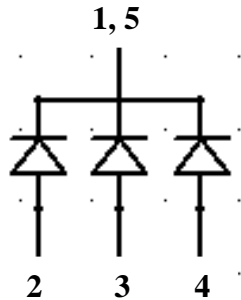
ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	TYP	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP ($I_f = 5\text{ A PER LEG}$) V_f $T_J=25\text{ }^\circ\text{C}$ $T_J=150\text{ }^\circ\text{C}$	1.65 2.55	1.80 3.00	Volts
MAXIMUM REVERSE CURRENT (1200V PIV PER LEG) I_r $T_J = 25\text{ }^\circ\text{C}$ $T_J = 150\text{ }^\circ\text{C}$	0.05 0.10	0.20 1.00	mA
TOTAL CAPACITANCE CHARGE ($V_R=1200\text{V}$, $I_f=5\text{A}$, $di/dt=500\text{A}/\mu\text{s}$ and $T_J=25\text{ }^\circ\text{C}$) Q_C per leg	28	N/A	nC

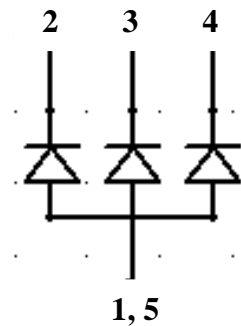
Application Note: Customers should be aware that at the current stage of technical development of SiC, the reverse avalanche capabilities of the device are limited.

Customer designs will need to accommodate these limitations and avoid exposure of the device to this and other potentially damaging conditions in their applications.

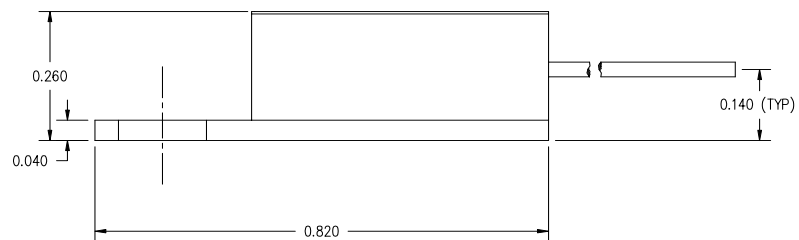
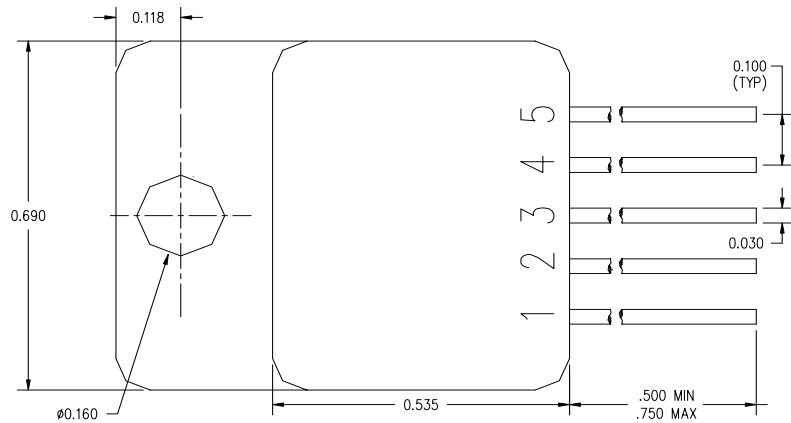
MECHANICAL DIMENSIONS (inches) (MO-078)



COMMON CATHODE



COMMON ANODE

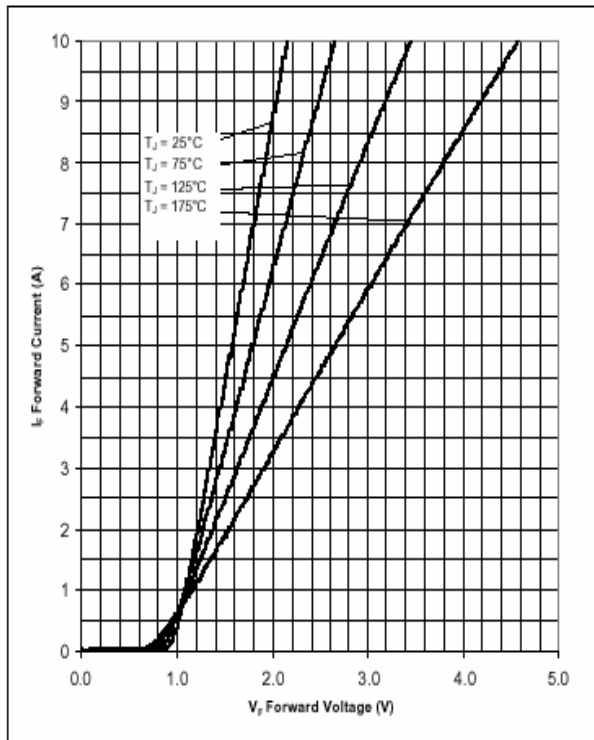
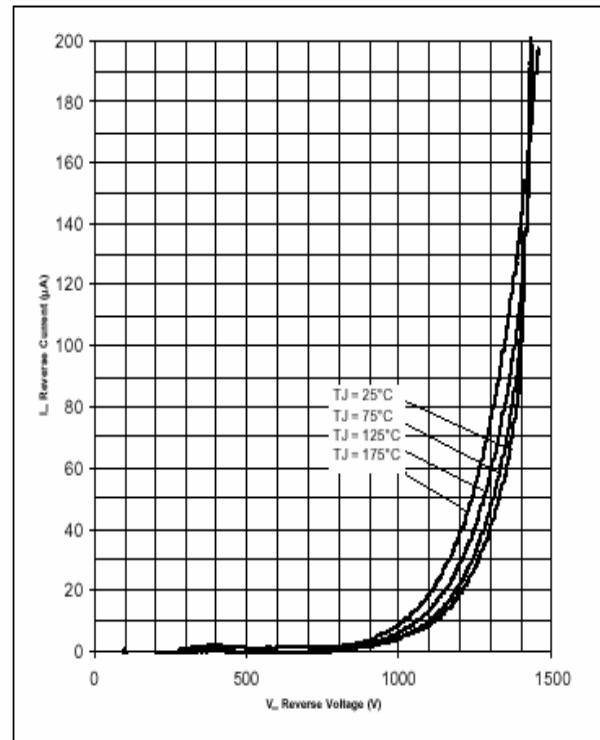


PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3	PIN 4	PIN 5
3-PHASE HALF WAVE BRIDGE COMMON CATHODE (SHB601052FP)	DC	AC(1)	AC(2)	AC(3)	DC
3-PHASE HALF WAVE BRIDGE COMMON ANODE (SHB601052FN)	DC	AC(1)	AC(2)	AC(3)	DC

SENSITRON

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Forward and Reverse Characteristics of Individual Diode**Figure 1. Forward Characteristics****Figure 2. Reverse Characteristics****DISCLAIMER:**

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